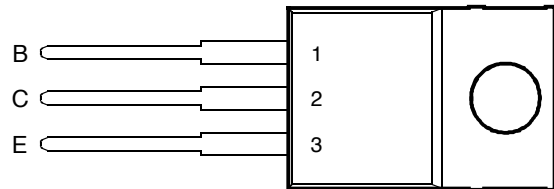


# BD242, BD242A, BD242B, BD242C PNP SILICON POWER TRANSISTORS

**BOURNS®**

- Designed for Complementary Use with the BD241 Series
- 40 W at 25°C Case Temperature
- 3 A Continuous Collector Current
- 5 A Peak Collector Current
- Customer-Specified Selections Available

TO-220 PACKAGE  
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA



This series is obsolete and not recommended for new designs.

## absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-emitter voltage ( $R_{BE} = 100 \Omega$ )	BD242	$V_{CER}$	-55	V
	BD242A		-70	
	BD242B		-90	
	BD242C		-115	
Collector-emitter voltage ( $I_C = -30 \text{ mA}$ )	BD242	$V_{CEO}$	-45	V
	BD242A		-60	
	BD242B		-80	
	BD242C		-100	
Emitter-base voltage		$V_{EBO}$	-5	V
Continuous collector current		$I_C$	-3	A
Peak collector current (see Note 1)		$I_{CM}$	-5	A
Continuous base current		$I_B$	-1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		$P_{tot}$	40	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		$P_{tot}$	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_C^2$	32	mJ
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	250	°C

NOTES: 1. This value applies for  $t_p \leq 0.3 \text{ ms}$ , duty cycle  $\leq 10\%$ .

2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20 \text{ mH}$ ,  $I_{B(on)} = -0.4 \text{ A}$ ,  $R_{BE} = 100 \Omega$ ,  $V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = -20 \text{ V}$ .

## PRODUCT INFORMATION

JUNE 1973 - REVISED SEPTEMBER 2002

Specifications are subject to change without notice.

# BD242, BD242A, BD242B, BD242C PNP SILICON POWER TRANSISTORS

**BOURNS®**

## electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = -30 \text{ mA}$ (see Note 5)	$I_B = 0$	BD242 BD242A BD242B BD242C	-45 -60 -80 -100			V
$I_{CES}$ Collector-emitter cut-off current	$V_{CE} = -55 \text{ V}$ $V_{CE} = -70 \text{ V}$ $V_{CE} = -90 \text{ V}$ $V_{CE} = -115 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD242 BD242A BD242B BD242C			-0.2 -0.2 -0.2 -0.2	mA
$I_{CEO}$ Collector cut-off current	$V_{CE} = -30 \text{ V}$ $V_{CE} = -60 \text{ V}$	$I_B = 0$ $I_B = 0$	BD242/242A BD242B/242C			-0.3 -0.3	mA
$I_{EBO}$ Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$				-1	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = -4 \text{ V}$ $V_{CE} = -4 \text{ V}$	$I_C = -1 \text{ A}$ $I_C = -3 \text{ A}$	(see Notes 5 and 6)	25 10			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = -0.6 \text{ A}$	$I_C = -3 \text{ A}$	(see Notes 5 and 6)			-1.2	V
$V_{BE}$ Base-emitter voltage	$V_{CE} = -4 \text{ V}$	$I_C = -3 \text{ A}$	(see Notes 5 and 6)			-1.8	V
$h_{fe}$ Small signal forward current transfer ratio	$V_{CE} = -10 \text{ V}$	$I_C = -0.5 \text{ A}$	$f = 1 \text{ kHz}$	20			
$ h_{fe} $ Small signal forward current transfer ratio	$V_{CE} = -10 \text{ V}$	$I_C = -0.5 \text{ A}$	$f = 1 \text{ MHz}$	3			

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

## thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			3.125	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

## resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
$t_{on}$ Turn-on time	$I_C = -1 \text{ A}$	$I_{B(on)} = -0.1 \text{ A}$	$I_{B(off)} = 0.1 \text{ A}$		0.2		$\mu\text{s}$
$t_{off}$ Turn-off time	$V_{BE(off)} = 3.7 \text{ V}$	$R_L = 20 \Omega$	$t_p = 20 \mu\text{s}$ , dc $\leq 2\%$		0.3		$\mu\text{s}$

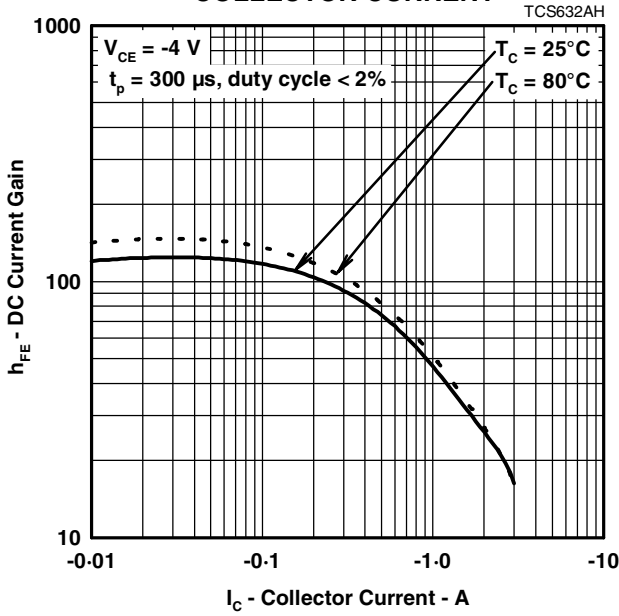
† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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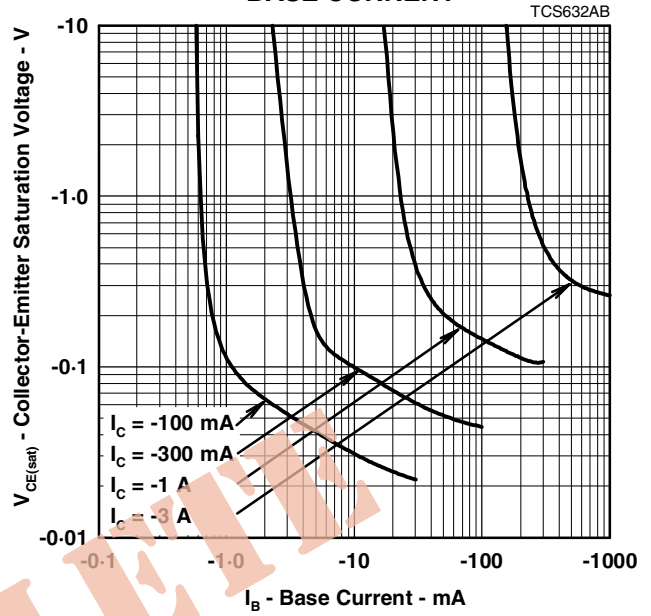
**TYPICAL CHARACTERISTICS**

**TYPICAL DC CURRENT GAIN  
vs  
COLLECTOR CURRENT**



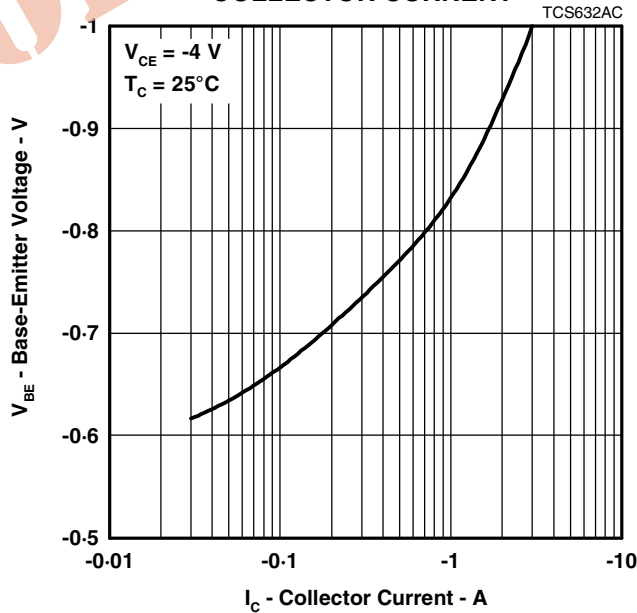
**Figure 1.**

**COLLECTOR-EMITTER SATURATION VOLTAGE  
vs  
BASE CURRENT**



**Figure 2.**

**BASE-EMITTER VOLTAGE  
vs  
COLLECTOR CURRENT**

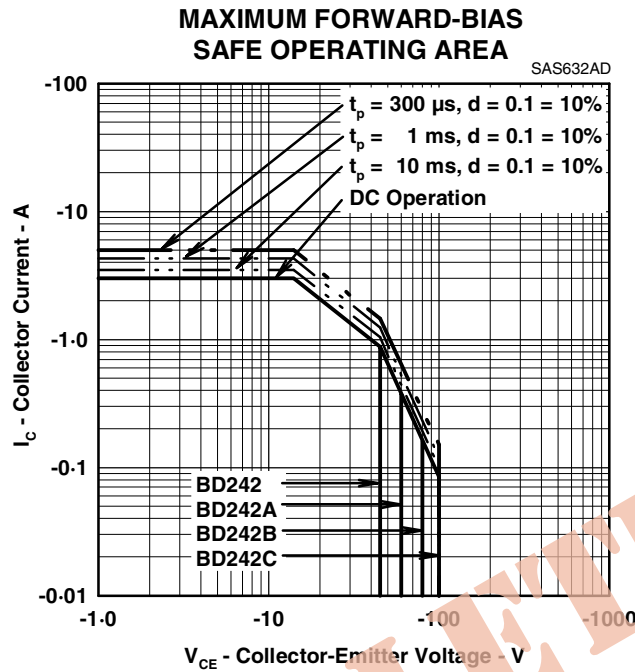


**Figure 3.**

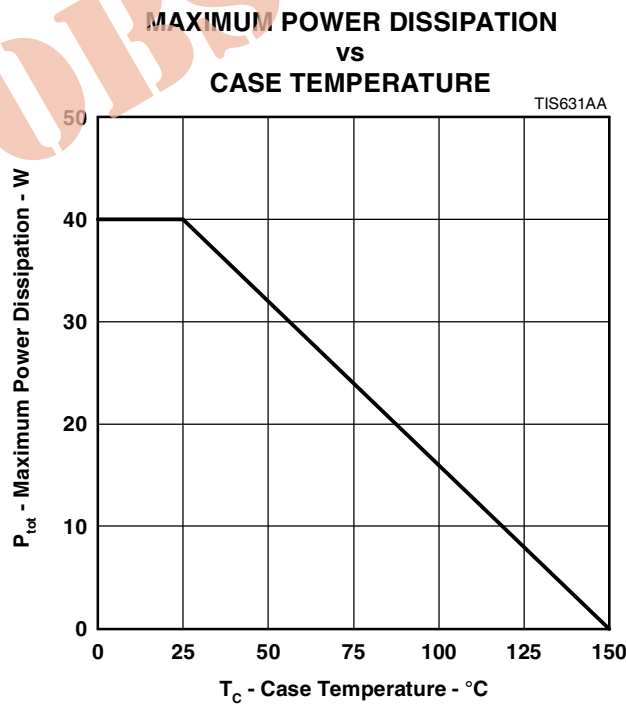
**PRODUCT INFORMATION**

JUNE 1973 - REVISED SEPTEMBER 2002  
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**MAXIMUM SAFE OPERATING REGIONS**



**THERMAL INFORMATION**



**PRODUCT INFORMATION**

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